

Mobility of proton conduction in thin films using the electric field effect

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The proton (H^+) transport properties of weak-acid polymer thin film, such as H^+ transport mobility (μ_{H^+}) and mobile H^+ concentration (n'_{H^+}), were revealed through a protonic field-effect transistor (H^+ -FET) with electrochemical impedance spectroscopy (EIS) measurement for the first time. H^+ -FET is a promising device for H^+ conductive materials investigation since it can control H^+ charge carrier flow by applying external gate voltage (V_g).¹⁻³ The H^+ charge carrier provided by the Pd electrode reaction with a DC measurement system is essential in the reported H^+ -FETs.^{1,2} However, we suspect that the excess H^+ carrier Pd electrode reaction and strong contact resistance effect might interfere with the material's properties investigation. Therefore, the H^+ -FET with the gold (Au) electrode coupling with EIS measurement under an air atmosphere was established to overcome the electrode reaction and contact resistance effects.

Our H^+ -FET device, named Au-CFET, consists of comb-shaped Au electrodes deposited on Si/SiO₂ substrate. Polyacrylic acid (PAA) thin film (45 nm) was spin-coated on Au-CFET and was investigated as H^+ conductive material.

The measurement was performed by individually applying V_g from -5 V to +5 V. We observed the V_g dependence of in-plane H^+ conductivity (σ), which increased when stronger negative V_g was applied (Fig. 1 (a)). The μ_{H^+} of $8 \times 10^{-4} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ was successfully estimated from the slope of the σ - V_g curve (-5 V to -3.5 V). As shown in Fig. 1 (b), we also discovered the influence of V_g on n'_{H^+} and the effective pK_a (pK'_a) of PAA thin film. Moreover, the V_g dependent of the film Debye length (κ^{-1}) would be further investigated.

1) C. Zhong, Y. Deng, A. F. Roudsari, A. Kapetanovic, M. P. Anantram, M. Rolandi, *Nat. Commun.* **2011**, 2, 476. 2) H. Zhong, G. Wu, Z. Fu, H. Lv, Xu. G, R. Wang, *Adv. Mater.* **2020**, 32, 2000730. 3) S. Mondal, Y. Agam, N. Amdursky, *Small* **2020**, 16, 2005526.

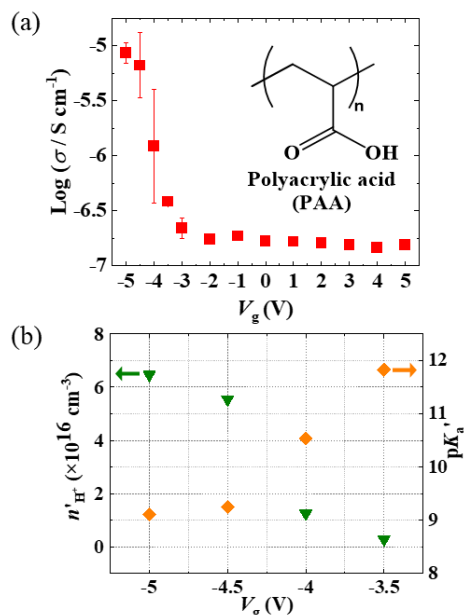


Figure 1 The applied V_g dependence of PAA thin film's (a) σ , and (b) n'_{H^+} and pK'_a .